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October 2014

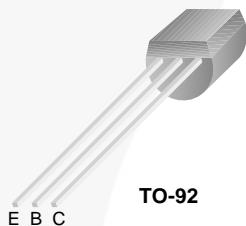
MPSA42 / MMBTA42 / PZTA42

NPN High-Voltage Amplifier

Features

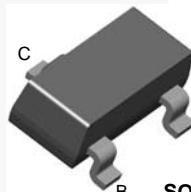
- This device is designed for application as a video output and other high-voltage applications.
- Sourced from process 48.

MPSA42

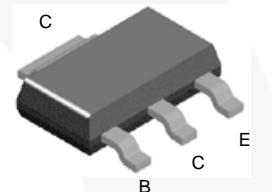


TO-92

MMBTA42

SOT-23
Mark: 1D

PZTA42



SOT-223

Ordering Information

Part Number	Top Mark	Package	Packing Method
MPSA42	MPSA42	TO-92 3L	Bulk
MMBTA42	1D	SOT-23 3L	Tape and Reel
PZTA42	A42	SOT-223 4L	Tape and Reel

Absolute Maximum Ratings^{(1), (2)}

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{CEO}	Collector-Emitter Voltage	300	V
V_{CBO}	Collector-Base Voltage	300	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current - Continuous	500	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Notes:

1. These ratings are based on a maximum junction temperature of 150°C .
2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

Thermal Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Max.			Unit
		MPSA42	MMBTA42 ⁽³⁾	PZTA42 ⁽⁴⁾	
P_D	Total Device Dissipation	625	240	1000	mW
	Derate Above 25°C	5.00	1.92	8.00	$\text{mW}/^\circ\text{C}$
$R_{\theta\text{JC}}$	Thermal Resistance, Junction-to-Case	83.3			$^\circ\text{C}/\text{W}$
$R_{\theta\text{JA}}$	Thermal Resistance, Junction-to-Ambient	200	515	125	$^\circ\text{C}/\text{W}$

Notes:

3. Device is mounted on FR-4 PCB 1.6 inch x 1.6 inch x 0.06 inch.
4. Device is mounted on FR-4 PCB 36 mm x 18 mm x 1.5 mm, mounting pad for the collector lead minimum 6 cm^2 .

Electrical Characteristics

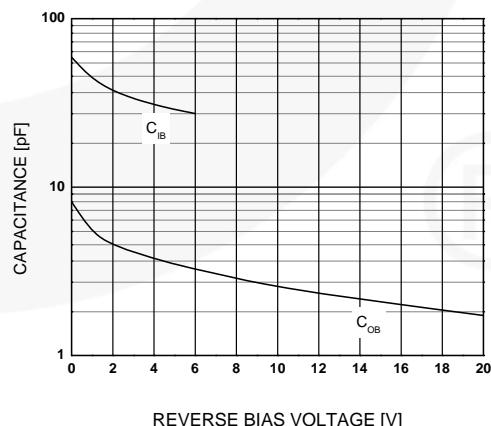
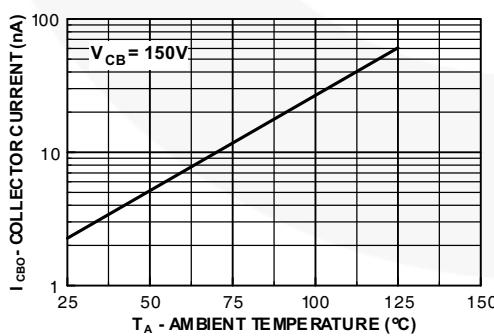
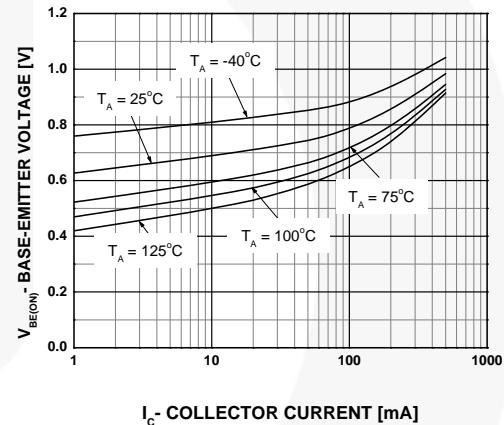
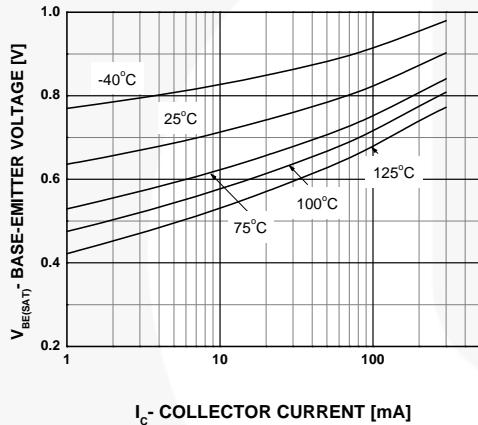
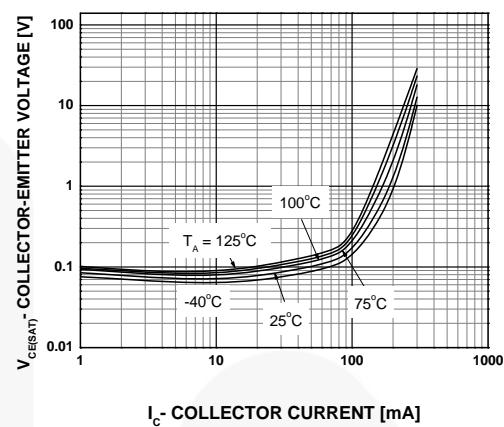
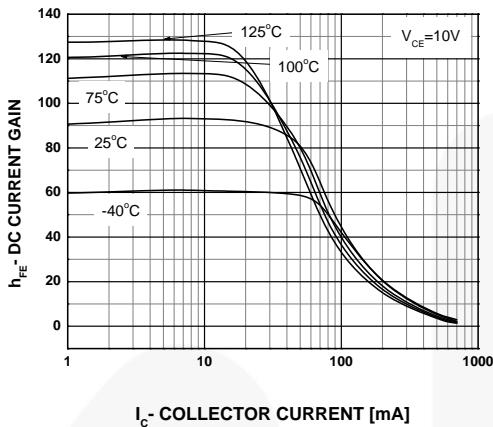
Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
Off Characteristics					
$V_{(\text{BR})\text{CEO}}$	Collector-Emitter Breakdown Voltage ⁽⁵⁾	$I_C = 1.0 \text{ mA}, I_B = 0$	300		V
$V_{(\text{BR})\text{CBO}}$	Collector-Base Breakdown Voltage	$I_C = 100 \mu\text{A}, I_E = 0$	300		V
$V_{(\text{BR})\text{EBO}}$	Emitter-Base Breakdown Voltage	$I_E = 100 \mu\text{A}, I_C = 0$	6		V
I_{CBO}	Collector Cut-Off Current	$V_{\text{CB}} = 200 \text{ V}, I_E = 0$		0.1	μA
I_{EBO}	Emitter Cut-Off Current	$V_{\text{EB}} = 6 \text{ V}, I_C = 0$		0.1	μA
On Characteristics⁽⁵⁾					
h_{FE}	DC Current Gain	$V_{\text{CE}} = 10 \text{ V}, I_C = 1.0 \text{ mA}$	25		
		$V_{\text{CE}} = 10 \text{ V}, I_C = 10 \text{ mA}$	40		
		$V_{\text{CE}} = 10 \text{ V}, I_C = 30 \text{ mA}$	40		
$V_{\text{CE}(\text{sat})}$	Collector-Emitter Saturation Voltage	$I_C = 20 \text{ mA}, I_B = 2.0 \text{ mA}$		0.5	V
$V_{\text{BE}(\text{sat})}$	Base-Emitter Saturation Voltage	$I_C = 20 \text{ mA}, I_B = 2.0 \text{ mA}$		0.9	V
Small Signal Characteristics					
f_T	Current Gain - Bandwidth Product	$I_C = 10 \text{ mA}, V_{\text{CE}} = 20 \text{ V}, f = 100 \text{ MHz}$	50		MHz
C_{cb}	Collector-Base Capacitance	$V_{\text{CB}} = 20 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$		3.0	pF

Notes:

5. Pulse test: pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$.

Typical Performance Characteristics



Typical Performance Characteristics (Continued)

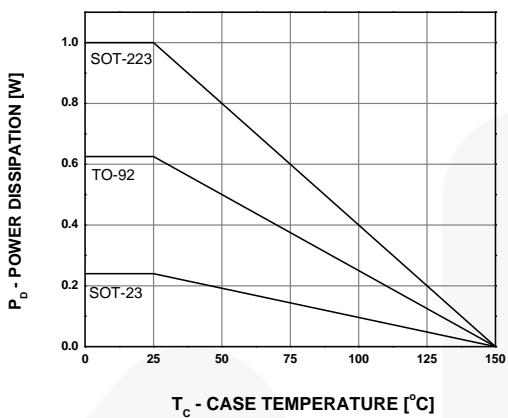
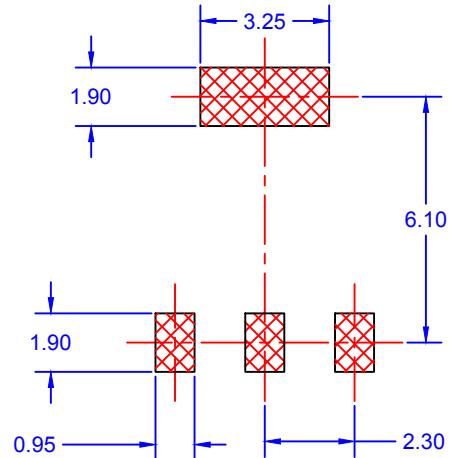
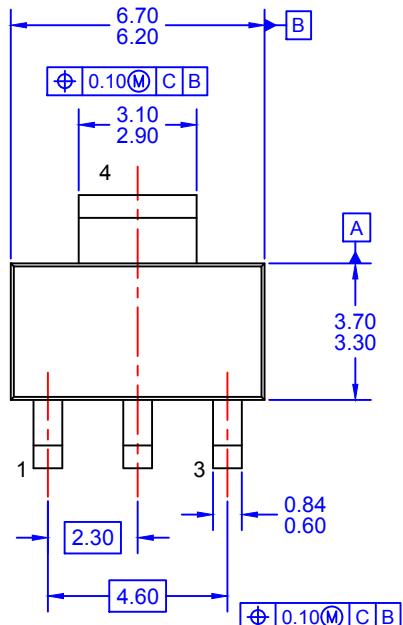
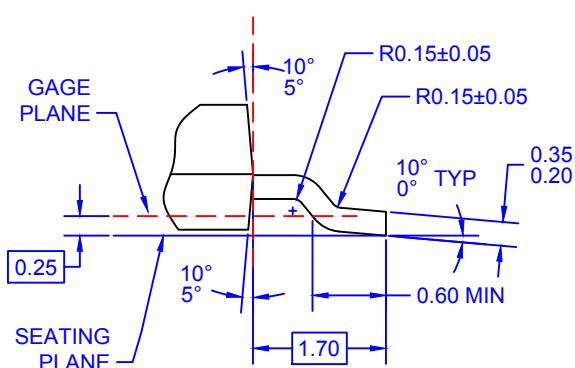
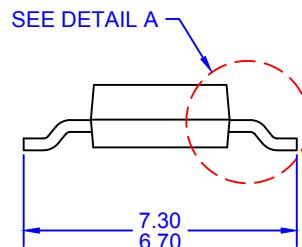
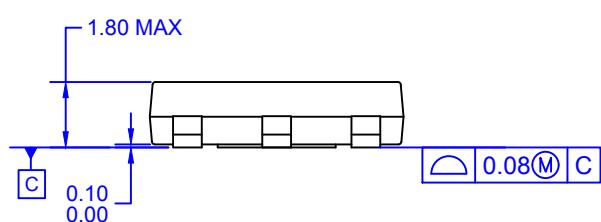


Figure 7. Power Dissipation vs. Ambient Temperature



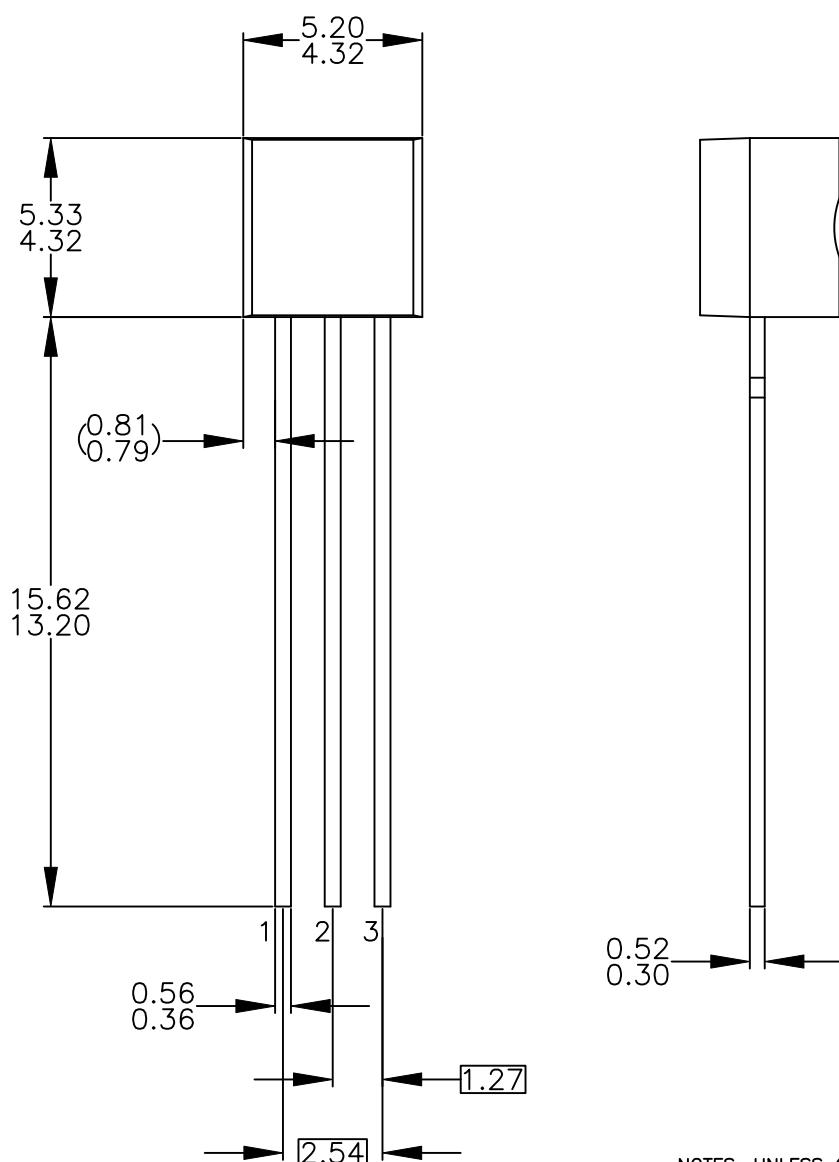
LAND PATTERN RECOMMENDATION



DETAIL A
SCALE: 2:1

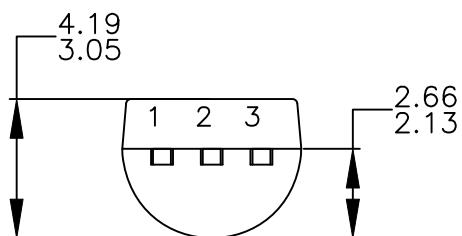
NOTES: UNLESS OTHERWISE SPECIFIED
 A) DRAWING BASED ON JEDEC REGISTRATION
 TO-261C, VARIATION AA.
 B) ALL DIMENSIONS ARE IN MILLIMETERS.
 C) DIMENSIONS DO NOT INCLUDE BURRS
 OR MOLD FLASH. MOLD FLASH OR BURRS
 DOES NOT EXCEED 0.10MM.
 D) DIMENSIONING AND TOLERANCING PER
 ASME Y14.5M-2009.
 E) LANDPATTERN NAME: SOT230P700X180-4BN
 F) DRAWING FILENAME: MKT-MA04AREV3

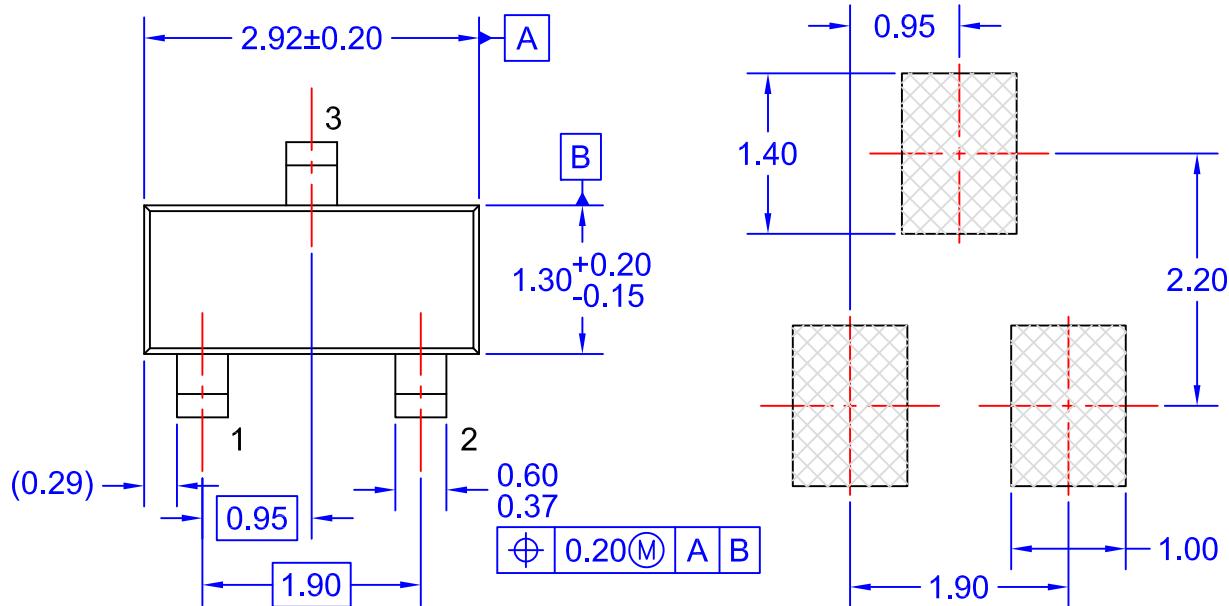




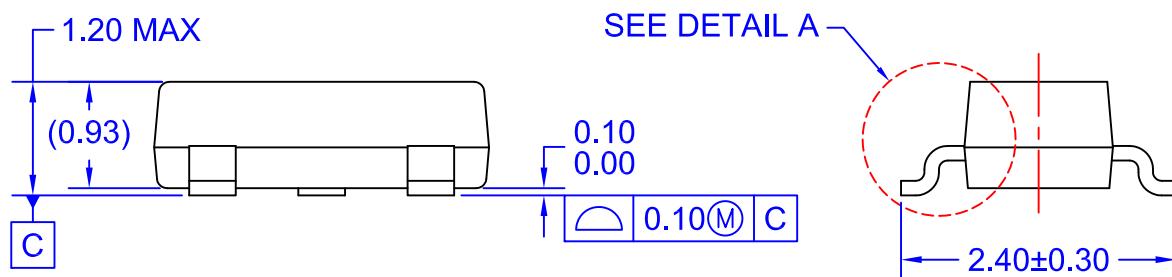
NOTES: UNLESS OTHERWISE SPECIFIED

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- C) DRAWING CONFORMS TO ASME Y14.5M-2009.
- D) DRAWING FILENAME: MKT-ZA03DREV4.

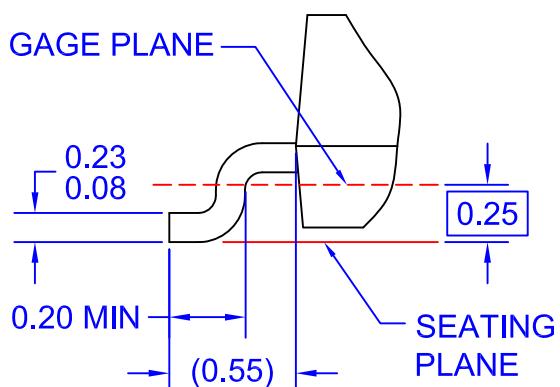




LAND PATTERN
RECOMMENDATION



NOTES: UNLESS OTHERWISE SPECIFIED



- A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 2009.
- E) DRAWING FILE NAME: MA03DREV12



DETAIL A
SCALE: 2X

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